Cat No.: Revision:

AllnGaP LED DICE

Part NO.: AOC-109YGxA-4mil Series

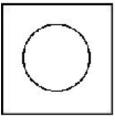
Features

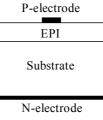
- Yellow green Color Emission
- Excellent performance and high efficiency
- Great reliability even in harsh environment

Description

AOC-109YGxA-4mil series is a yellow green color emitting AlInGaP LED grown by MOCVD technique. Its structure enables enhanced quantum efficiency and therefore a greater light intensity. This device is designed to suit the growing demand in the compact size electronic goods.

Chip Dimensions





Chip Size : 7.7mil×7.7mil±0.5mil Bonding Pad : ϕ 4.0mil±0.4mil Chip Thickness : 4.0mil±1.0mil

Specification and Optical Characteristics

Measuring Item	Symbol	Condition	Min	Тур	Max	Unit
Forward Voltage	V_{F}	I _F =20mA	1.70	-	2.30	V
Reverse Current	Ir	VR=-5V	-	-	1.0	μA
Dominant Wavelength	λd	I _F =20mA	567	-	577	nm
Max. Junction Temperature	T _{max}	-	\leq 115			°C
Max. DC forward current	I_{f}	$Ta = 25^{\circ}C$	\leq 30			mA
Max. pulse forward current	I_{fm}	$Ta = 25^{\circ}C$	\leq 60			mA
(Pulse width 0.1 msec, frequency=1 kHz.)	1 _{fm}					
Storage temperature	T _{stg}	Chip on tape	$0 \sim 40$			°C
		Only chip	$-40 \sim 80$			

Available Dominate Wavelength and Iv Matrix

Part No.	Wavelength Range	$\geq 10 \text{ mcd}$	$\geq 20 \text{ mcd}$	\geq 30 mcd	\geq 40 mcd	$\geq 50 \text{ mcd}$	$\geq 60 \text{ mcd}$	\geq 70 mcd
109 YGSA-4	567 ~ 573 nm	-	-	В	С	D	-	-
109 YGLA-4	571 ~ 577 nm	-	-	-	С	D	Е	-

Not:

1. All measurements are done with AOC's standard testing equipment.

2. Luminance intensity is measured on bare chip.

Above contents are subject to change without notice.
Special requests are also welcome, please contact AOC's sale representative for any request.